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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 4

Complete if Known	
Application Number	10/810,963
Filing Date	March 26, 2004
First Named Inventor	Rueckes, Thomas et al.
Art Unit	2818
Examiner Name	TBA
Attorney Docket Number	112020.146US2 NAN-22

U. S. PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Document Number Number-Kind Code[2](if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Examiner Signature		Date Considered	11/02/05

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Examiner Initials*	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T[2]
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DN		WO 04/065657 A1	08-05-2004	Nantero, Inc.	

NON PATENT LITERATURE DOCUMENTS

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